National Semiconductor

July 1998

54ABT244
Octal Buffer/Line Driver with TRI-STATE® Outputs

General Description

The 'ABT244 is an octal buffer and line driver with TRI-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus-oriented transmitter/receiver.

Features

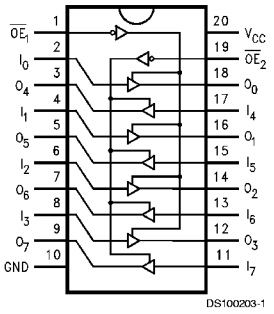
- Non-inverting buffers
- Output sink capability of 48 mA, source capability of 24 mA
- Output switching specified for both 50 pF and 250 pF loads
- Guaranteed simultaneous switching, noise level and dynamic threshold performance
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Nondestructive hot insertion capability
- Disable time less than enable time to avoid bus contention
- Standard Microcircuit Drawing (SMD) 5962-9214701

Ordering Code

Military	Package Number	Package Description
54ABT244J-QML	J20A	20-Lead Ceramic Dual-In-Line
54ABT244W-QML	W20A	20-Lead Cerpack
54ABT244E-QML	E20A	20-Lead Ceramic Leadless Chip Carrier, Type C

Connection Diagrams

Pin Assignment for DIP and Flatpak



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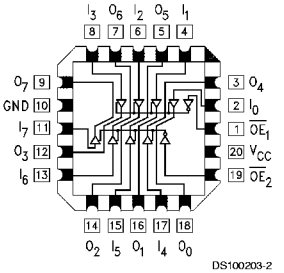
Pin Assignment for LCC



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Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	Output Enable Input (Active Low)
I_0–I_7	Inputs
O_0–O_7	Outputs

Truth Table

$\overline{OE}_1$	I_{0-3}	O_{0-3}	$\overline{OE}_2$	I_{4-7}	O_{4-7}
H	X	Z	H	X	Z
L	H	H	L	H	H
L	L	L	L	L	L

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

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Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	
Ceramic	−55°C to +175°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disabled or	
Power-Off State	−0.5V to 5.5V
in the HIGH State	−0.5V to V_{CC}
Current Applied to Output	
in LOW State (Max)	twice the rated I_{OL} (mA)
DC Latchup Source Current	−500 mA
Over Voltage Latchup (I/O)	10V

Recommended Operating Conditions

Free Air Ambient Temperature	
Military	−55°C to +125°C
Supply Voltage	
Military	+4.5V to +5.5V
Minimum Input Edge Rate	(ΔV/Δt)
Data Input	50 mV/ns
Enable Input	20 mV/ns

DC Electrical Characteristics

Symbol	Parameter		ABT244 Min	ABT244 Typ	ABT244 Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	54ABT	2.5			V	Min	I_{OH} = −3 mA
		54ABT	2.0			V	Min	I_{OH} = −24 mA
V_{OL}	Output LOW Voltage	54ABT			0.55	V	Min	I_{OL} = 48 mA
I_{IH}	Input HIGH Current				5	μA	Max	V_{IN} = 2.7V (Note 4)
					5			V_{IN} = V_{CC}
I_{BVI}	Input HIGH Current Breakdown Test				7	μA	Max	V_{IN} = 7.0V
I_{IL}	Input LOW Current				−5	μA	Max	V_{IN} = 0.5V (Note 4)
					−5			V_{IN} = 0.0V
V_{ID}	Input Leakage Test		4.75			V	0.0	I_{ID} = 1.9 μA All Other Pins Grounded
I_{OZH}	Output Leakage Current				50	μA	0 – 5.5V	V_{OUT} = 2.7V; $\overline{OE}_n$ = 2.0V
I_{OZL}	Output Leakage Current				−50	μA	0 – 5.5V	V_{OUT} = 0.5V; $\overline{OE}_n$ = 2.0V
I_{OS}	Output Short-Circuit Current		−100		−275	mA	Max	V_{OUT} = 0.0V
I_{CEX}	Output High Leakage Current				50	μA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test				100	μA	0.0	V_{OUT} = 5.5V; All Others GND
I_{CCH}	Power Supply Current				50	μA	Max	All Outputs HIGH
I_{CCL}	Power Supply Current				30	mA	Max	All Outputs LOW
I_{CCZ}	Power Supply Current				50	μA	Max	$\overline{OE}_n$ = V_{CC}; All Others at V_{CC} or Ground
I_{CCT}	Additional I_{CC}/Input	Outputs Enabled			2.5	mA	Max	V_I = V_{CC} − 2.1V
		Outputs TRI-STATE			2.5	mA		Enable Input V_I = V_{CC} − 2.1V
		Outputs TRI-STATE			50	μA		Data Input V_I = V_{CC} − 2.1V All Others at V_{CC} or Ground
I_{CCD}	Dynamic I_{CC}	No Load				mA/	Max	Outputs Open
	(Note 4)				0.1	MHz		$\overline{OE}_n$ = GND, (Note 3) One Bit Toggling, 50% Duty Cycle

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Note 3: For 8 bits toggling, I_{CCD} < 0.8 mA/MHz.

Note 4: Guaranteed, but not tested.

AC Electrical Characteristics

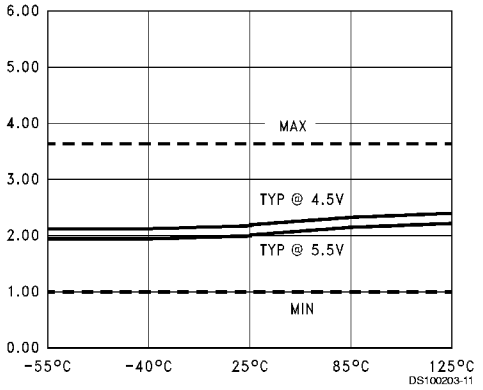
Symbol	Parameter	54ABT $T_A = -55°C$ to $+125°C$, $V_{CC} = 4.5V–5.5V$, $C_L = 50$ pF		Units	Fig. No.
		Min	Max		
t_{PLH}	Propagation Delay	1.0	5.3	ns	*Figure 5*
t_{PHL}	Data to Outputs	1.0	5.0		
t_{PZH}	Output Enable	0.8	6.5	ns	*Figure 4*
t_{PZL}	Time	1.2	7.9		
t_{PHZ}	Output Disable	1.2	7.6	ns	*Figure 4*
t_{PLZ}	Time	1.0	7.9		

Capacitance

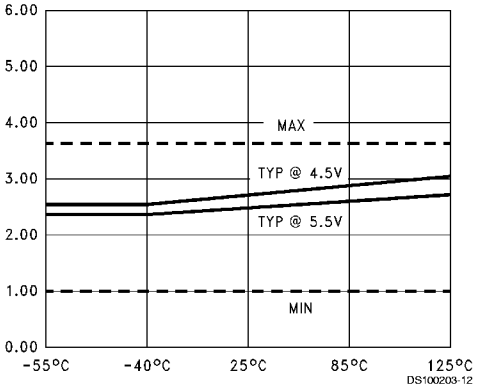
Symbol	Parameter	Typ	Units	Conditions $T_A = 25°C$
C_{IN}	Input Capacitance	5.0	pF	$V_{CC} = 0V$
C_{OUT} (Note 5)	Output Capacitance	9.0	pF	$V_{CC} = 5.0V$

Note 5: C_{OUT} is measured at frequency f = 1 MHz, per MIL-STD-883B, Method 3012.

t_{PLH} vs Temperature (T_A)
C_L = 50 pF, 1 Output Switching



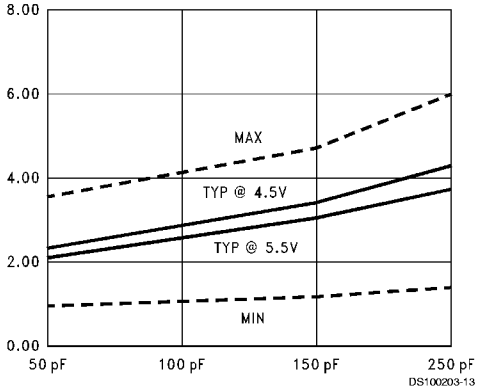
t_{PHL} vs Temperature (T_A)
C_L = 50 pF, 1 Output Switching



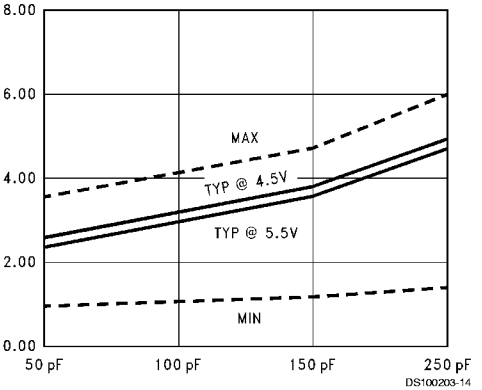
Dashed lines represent design characteristics; for specified guarantees refer to AC Characteristics Table.

Capacitance (Continued)

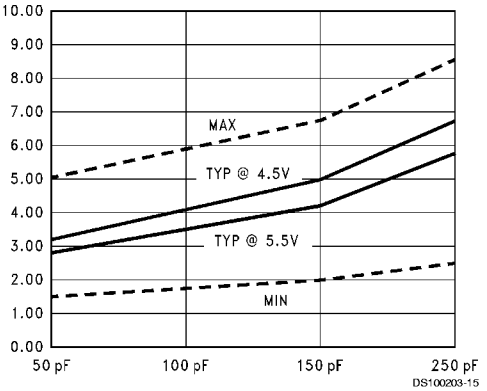
t_{PLH} vs Load Capacitance
1 Output Switching, T_A = 25˚C



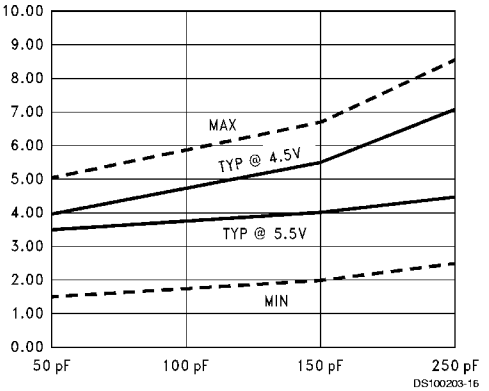
t_{PHL} vs Load Capacitance
1 Output Switching, T_A = 25˚C



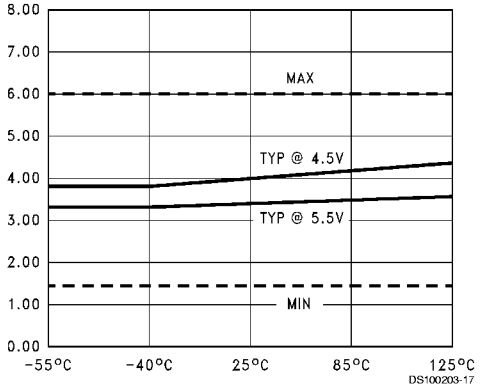
t_{PLH} vs Load Capacitance
8 Outputs Switching, T_A = 25˚C



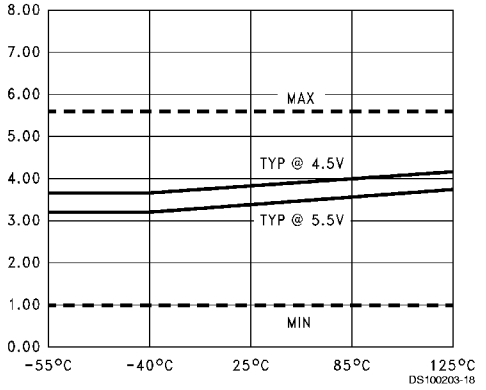
t_{PHL} vs Load Capacitance
8 Outputs Switching, T_A = 25˚C



t_{PZL} vs Temperature (T_A)
C_L = 50 pF, 1 Output Switching



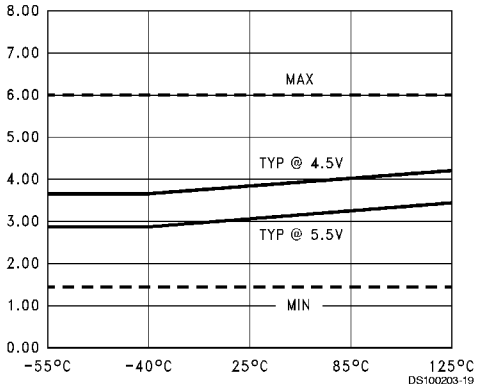
t_{PLZ} vs Temperature (T_A)
C_L = 50 pF, 1 Output Switching



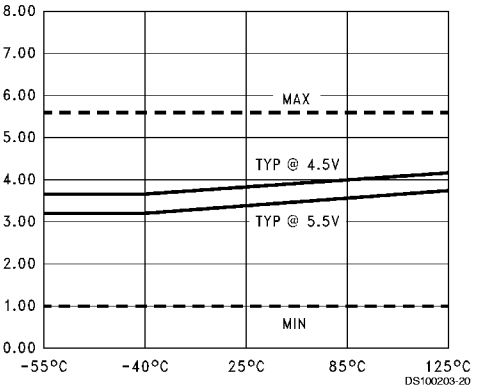
Dashed lines represent design characteristics; for specified guarantees refer to AC Characteristics Table.

Capacitance (Continued)

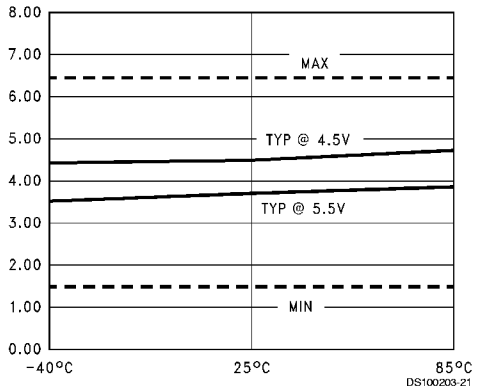
t_{PZH} vs Temperature (T_A)
C_L = 50 pF, 1 Output Switching



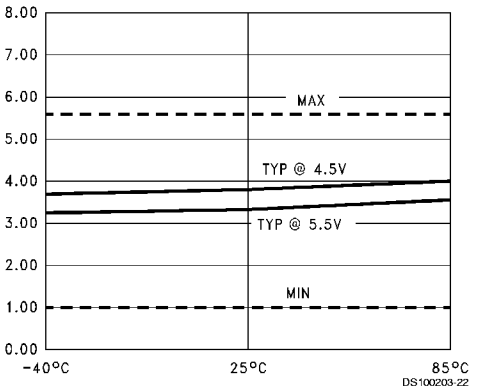
t_{PHZ} vs Temperature (T_A)
C_L = 50 pF, 1 Output Switching



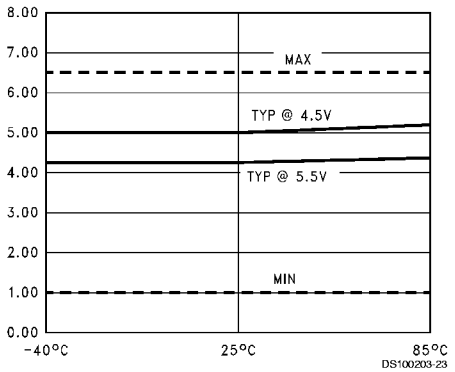
t_{PZH} vs Temperature (T_A)
C_L = 50 pF, 8 Outputs Switching



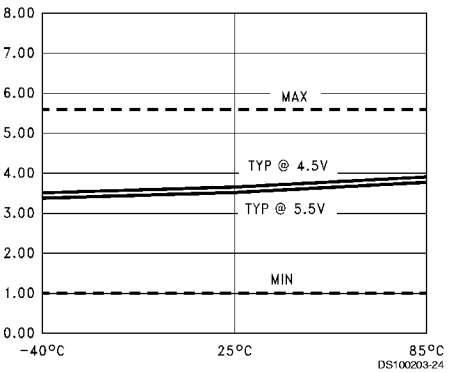
t_{PHZ} vs Temperature (T_A)
C_L = 50 pF, 8 Outputs Switching



t_{PZL} vs Temperature (T_A)
C_L = 50 pF, 8 Outputs Switching



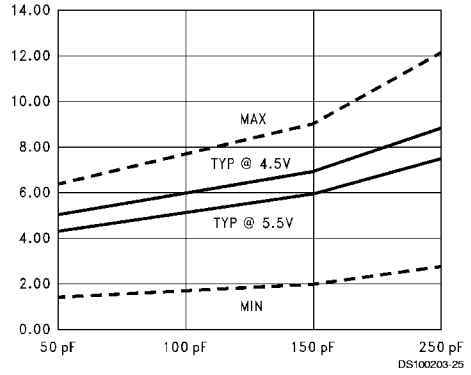
t_{PLZ} vs Temperature (T_A)
C_L = 50 pF, 8 Outputs Switching



Dashed lines represent design characteristics; for specified guarantees refer to AC Characteristics Table.

Capacitance (Continued)

t_{PZL} vs Load Capacitance
8 Outputs Switching
T_A = 25°C



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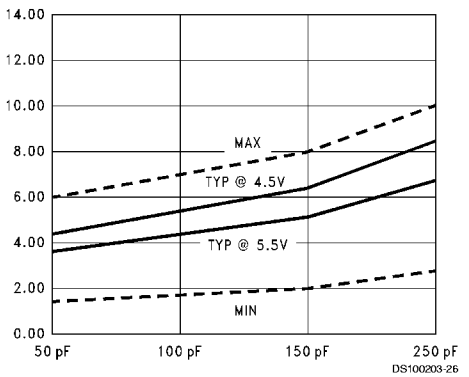
t_{PZH} vs Load Capacitance
8 Outputs Switching
T_A = 25°C



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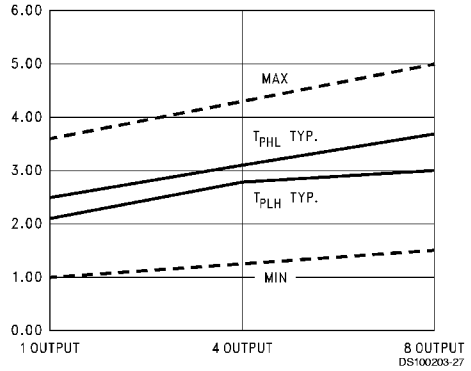
t_{PLH} and t_{PHL} vs Number
Outputs Switching V_{CC} = 5.0V,
T_A = 25°C, C_L = 50 pF



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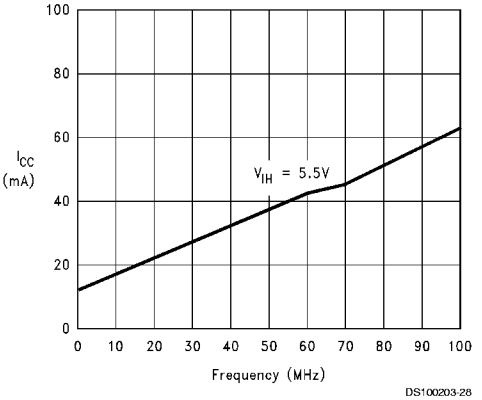
I_{CC} vs Frequency,
Average, T_A = 25°C,
All Outputs Unloaded/Unterminated



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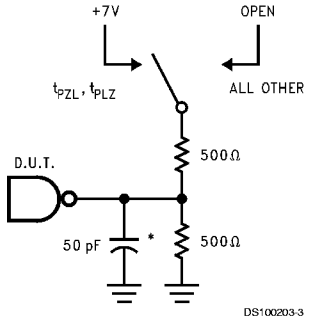
Dashed lines represent design characteristics; for specified guarantees refer to AC Characteristics Table.

AC Loading



*Includes jig and probe capacitance

FIGURE 1. Standard AC Test Load

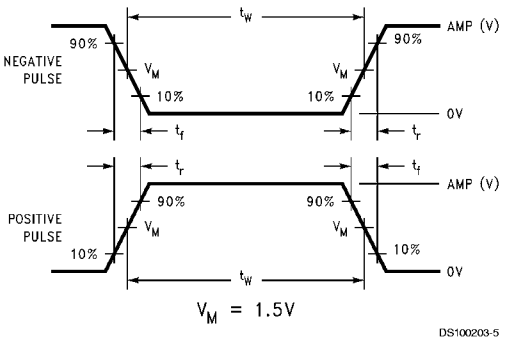


FIGURE 2. Test Input Signal Levels

Amplitude	Rep. Rate	t_W	t_r	t_f
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 3. Test Input Signal Requirements

AC Waveforms

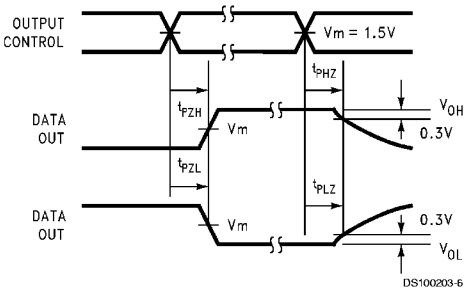


FIGURE 4. TRI-STATE Output HIGH and LOW Enable and Disable Times

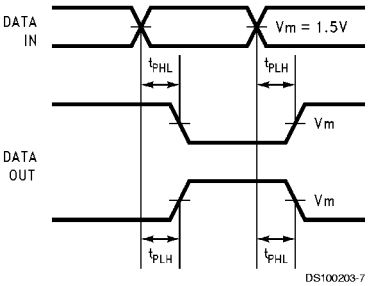
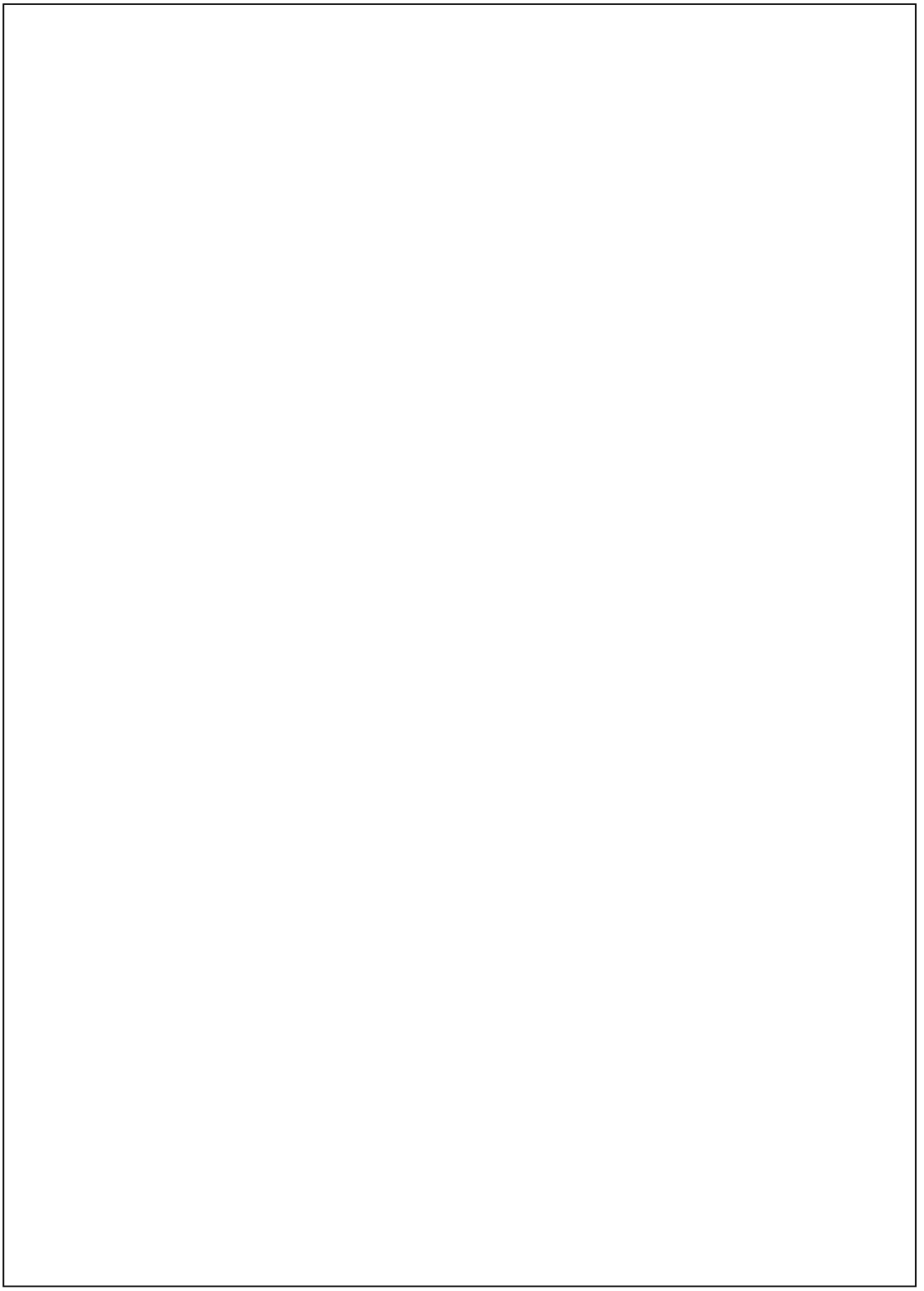
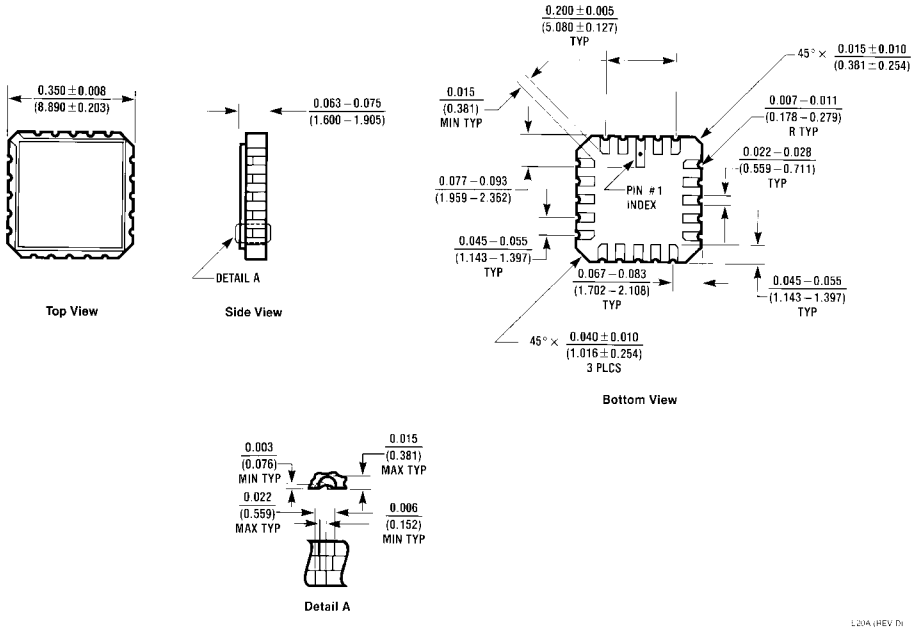


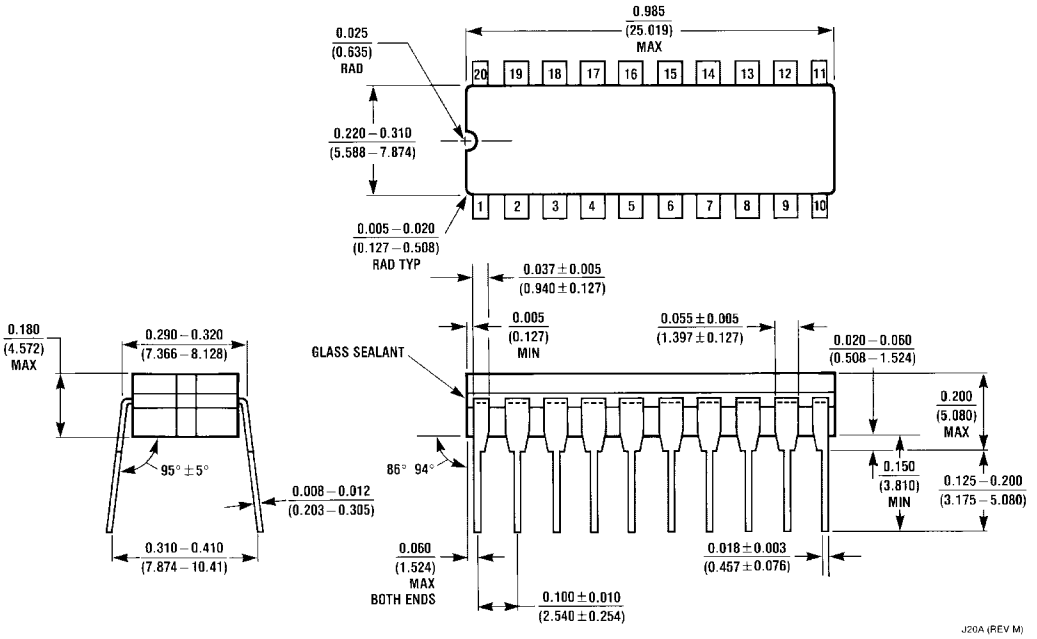
FIGURE 5. Propagation Delay Waveforms for Inverting and Non-Inverting Functions



Physical Dimensions inches (millimeters) unless otherwise noted

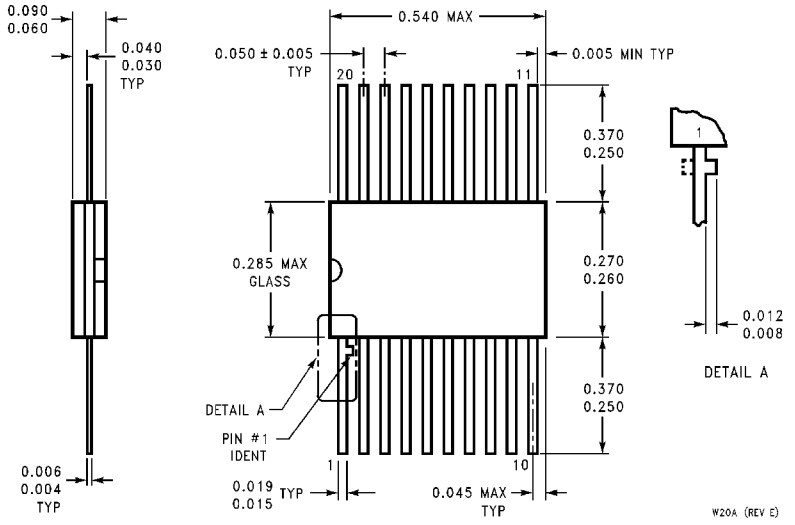


20-Terminal Ceramic Chip Carrier (L)
NS Package Number E20A



20-Lead Ceramic Dual-In-Line (D)
NS Package Number J20A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead Ceramic Flatpak (F)
NS Package Number W20A

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